

SOT23 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

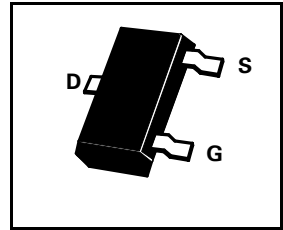
ZVP1320F

ISSUE 3 – JANUARY 1996 

FEATURES

* $V_{DS} - 200V$

PARTMARKING DETAIL - MT



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	V_{DS}	-200	V
Continuous Drain Current at $T_{amb}=25^{\circ}C$	I_D	-35	mA
Pulsed Drain Current	I_{DM}	-400	mA
Gate Source Voltage	V_{GS}	± 20	V
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +150	$^{\circ}C$

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

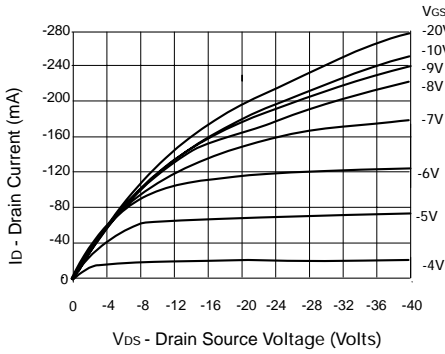
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV_{DSS}	-200		V	$I_D=-1mA, V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	-1.5	-3.5	V	$I_D=-1mA, V_{DS}=V_{GS}$
Gate-Body Leakage	I_{GSS}		20	nA	$V_{GS}=\pm 20V, V_{DS}=0V$
Zero Gate Voltage Drain Current	I_{DSS}		-10 -50	μA μA	$V_{DS}=-200V, V_{GS}=0V$ $V_{DS}=-160V, V_{GS}=0V,$ $T=125^{\circ}C(2)$
On-State Drain Current(1)	$I_{D(on)}$	-100		mA	$V_{DS}=-25V, V_{GS}=-10V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		80	Ω	$V_{GS}=-10V, I_D=-50mA$
Forward Transconductance (1)(2)	g_{fs}	25		mS	$V_{DS}=-25V, I_D=-50mA$
Input Capacitance (2)	C_{iss}		50	pF	$V_{DS}=-25V, V_{GS}=0V, f=1MHz$
Common Source Output Capacitance (2)	C_{oss}		15	pF	
Reverse Transfer Capacitance (2)	C_{rss}		5	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		8	ns	$V_{DD}=-25V, I_D=-50mA$
Rise Time (2)(3)	t_r		8	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		8	ns	
Fall Time (2)(3)	t_f		16	ns	

(1) Measured under pulsed conditions. Width=300 μs . Duty cycle $\leq 2\%$ (2) Sample test.

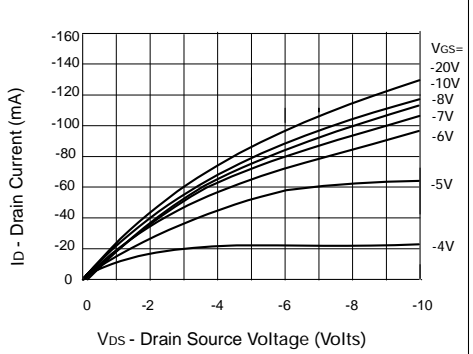
(3) Switching times measured with 50 Ω source impedance and <5ns rise time on a pulse generator

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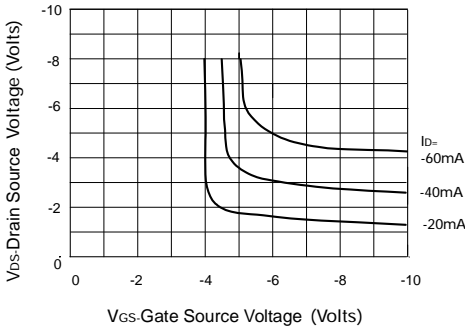
TYPICAL CHARACTERISTICS



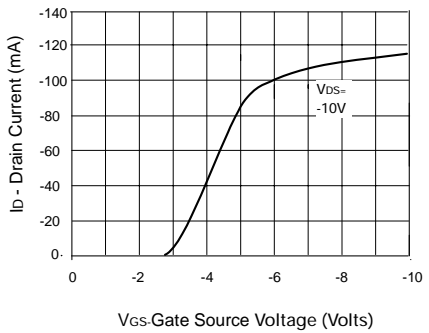
Output Characteristics



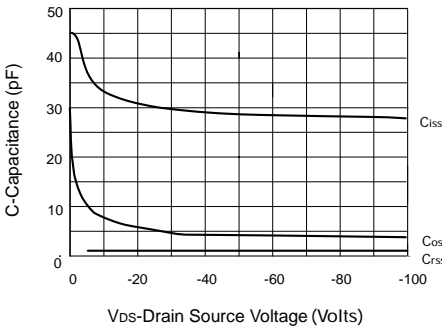
Saturation Characteristics



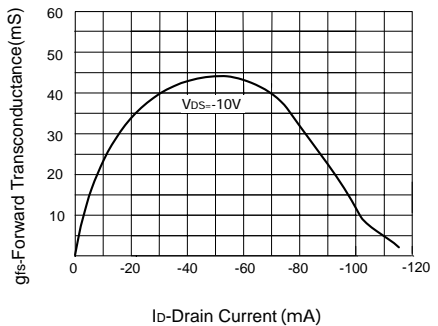
Voltage Saturation Characteristics



Transfer Characteristics



Capacitance v drain-source voltage



Transconductance v drain current

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TYPICAL CHARACTERISTICS

